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Yb³⁺ and Yb³⁺/Er³⁺ Doping for Near-Infrared Emission and Improved Stability of CsPbCl₃ Nanocrystals†

Xiangtong Zhang^a, Yu Zhang^a, Xiaoyu Zhang^b, Wenxu Yin^a, Yu Wang^a, Hua Wang^c, Min Lu^a, Zhiyang Li^d, Zhiyong Gu^d, and William W. Yu^c

^aState Key Laboratory of Integrated Optoelectronics and College of Electronic Science and Engineering, Jilin University, Changchun, 130012, China.

^bSchool of Materials Science & Engineering, Jilin University, Changchun 130012, China

^cDepartment of Chemistry and Physics, Louisiana State University, Shreveport, LA 71115, USA.

^dDepartment of Chemical Engineering, University of Massachusetts Lowell, Lowell, MA 01854, USA

Abstract

Lead halide perovskite nanocrystals (NCs) exhibit excellent tunable emissions covering the entire visible spectral region, but they do not emit near-infrared (NIR) light. We synthesized rare earth element doped CsPbCl₃ NCs for NIR emission. The Yb³⁺ doped CsPbCl₃ NCs emitted strong 986 nm NIR light; the Yb³⁺/Er³⁺ co-doped CsPbCl₃ NCs emitted at 1533 nm. The total photoluminescence quantum yield (PL QY) of the CsPbCl₃ NCs changed from 5.0% to 127.8% upon incorporating 2.0% Yb³⁺, a factor of 25.6 times enhancement. The material's stability was tested under continuous ultraviolet (365 nm) irradiation. The doped CsPbCl₃ NCs exhibited a better stability than the undoped one. The PL intensity of the undoped CsPbCl₃ NCs dropped to 20% of the initial value in 27 h, while the doped one took 85 h.

Introduction

With facile tunability of emission over the whole visible spectrum, nonblinking characteristic, large absorption coefficient, narrow emission line widths and near-unit quantum yields (QYs),^{1–6} lead halide perovskite nanocrystals (NCs) have attracted intensive attention as excellent materials for a wide range of applications including high-efficient solar cells,⁷ light-emitting diodes and lasing.^{8–13} Perovskite NCs with a formula APbX₃ [A = Cs⁺, CH₃NH₃⁺, or CH(NH₂)₂⁺; X = Cl[−], Br[−], I[−], or their mixtures] obey the tolerance factor and octahedral factor in structures.^{14–16} These two factors also make these perovskite NCs tolerant to doped elements. Doping is an effective way to adjust the electronic and optical performances or to improve the stability.^{17,18} In fact, many reports have validated the facile doping in lead halide perovskites due to their non-rigid structures. For example, Ag⁺, K⁺, Rb

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Corresponding authors: yuzhang@jlu.edu.cn (Y. Zhang), wyu6000@gmail.com (W. W. Yu).

Conflicts of interest

There are no conflicts to declare.

$^{+}$, Sn^{4+} , Sn^{2+} , Zn^{2+} , Cd^{2+} , Bi^{3+} and Mn^{2+} have been applied as dopants,^{19–26} but none of them can enable near-infrared (NIR) emissions.

Rare earth (RE) elements usually act as PL centers in many host materials such as oxides, fluorides and semiconductors.^{27–30} Owing to the strong shielding effect from the eight electrons in their outer 5s and 5p electronic orbitals, the partially filled 4f electronic orbital have various energy levels. These electrons jumping among the different energy levels generate various narrow width emissions ranging from UV to IR and thus there are many useful applications such as multimodal imaging probes, temperature sensing, lighting devices and theranostics.^{31–35} The luminescence of RE ions can be sensitized by various energy transfer channels.³⁶ There are mainly two reasons for CsPbCl_3 NCs to be chosen as a luminescent acceptor: lead halide perovskites have large absorption coefficients;⁶ CsPbCl_3 NCs have a large band gap among lead halide perovskites, which is appropriate for exciton energy transfer.³⁷ It is highly desirable to successfully link the absorption of lead halide perovskite NCs and the IR emission of RE elements.

Recently, Pan *et al.* doped several lanthanide elements into CsPbCl_3 NCs and showed interesting changes.³⁸ Milstein *et al.* provided insights into the microscopic mechanism behind the extremely efficient sensitization of Yb^{3+} luminescence in CsPbX_3 NCs.³⁹ Here, we report a successful synthesis of colloidal $\text{CsPbCl}_3:\text{Yb}^{3+}$, $\text{CsPbCl}_3:\text{Er}^{3+}$ and $\text{CsPbCl}_3:\text{Yb}^{3+}/\text{Er}^{3+}$ NCs by a modified hot-injection method, which is simpler and more effective. The optimal doping level was 2.0% for the $\text{CsPbCl}_3:\text{Yb}^{3+}$ NCs; the total photoluminescence (PL) QY was 127.8% with both the band edge and 986 nm NIR emissions. Besides, we also acquired emission at 1533 nm from the $\text{Yb}^{3+}/\text{Er}^{3+}$ co-doped CsPbCl_3 NCs. These doped NCs may be applied to NIR diode lasers and photo-communications.

Experimental

Materials

Cs_2CO_3 (99.995%, Sigma-Aldrich), 1-octadecene (ODE, technical grade 90%, Sigma-Aldrich), oleic acid (OA, technical grade 90%, Sigma-Aldrich), oleylamine (OAm, 80–90%, Aladdin), lead acetate trihydrate ($\text{Pb}(\text{OAc})_2 \cdot 3\text{H}_2\text{O}$, 99.99% metal basis, Aladdin), lead(II) chloride (PbCl_2 , 99.999% metal basis, Sigma-Aldrich), ytterbium chloride hexahydrate ($\text{YbCl}_3 \cdot 6\text{H}_2\text{O}$, 99.9% metal basis, Aladdin), erbium chloride hexahydrate ($\text{ErCl}_3 \cdot 6\text{H}_2\text{O}$, 99.9% metal basis, Aladdin), and toluene (GR, Beijing Chemical Reagent Ltd) were used as received.

Preparation of Cs-oleate solution

A cesium-oleate solution was prepared according to the approach reported by Protesescu *et al.*¹ Briefly, 0.814 g of Cs_2CO_3 , 2.5 ml of OA and 30 ml of ODE were loaded in a 100 ml three-neck round bottom flask and degassed under vacuum at 120 °C for 1 h. Then, the flask was filled with flowing N_2 gas and heated up to 150 °C until all Cs_2CO_3 reacted with OA. The solution was then cooled down to room temperature naturally and stored under N_2 protection.

Preparation of the CsPbCl₃ NCs

PbCl₂ (0.376 mmol), OA (1 ml), OAm (1 ml) and ODE (10 ml) were added to a 50 ml three-neck round bottom flask and dried under vacuum at 120 °C for 1 h. Then the temperature was increased to 180 °C under flowing N₂. A preheated (100 °C) 0.8 ml Cs-oleate solution was swiftly injected using a syringe. After 5 s, the flask was immersed in an ice bath to stop the reaction.

Preparation of the single doped CsPbCl₃ NCs with Yb³⁺ or Er³⁺

Typically, 0.376 mmol of YbCl₃·6H₂O (or ErCl₃·6H₂O) and 0.123 mmol of Pb(OAc)₂·3H₂O were mixed with 2 ml of OA, 2 ml of OAm and 10 ml of ODE in a 50 ml quartz three-neck round bottom flask. After being degassed under vacuum at 120 °C for 1 h, the reactants were completely dissolved and the flask was switched to a N₂ atmosphere. The temperature was quickly increased to 260 °C and maintained for 3 min. Then, a preheated (100 °C) 0.8 ml Cs-oleate solution was swiftly injected *via* a syringe. 5 s later, the flask was immersed into an ice bath to stop the reaction. It should be pointed out that a quartz flask was used to tolerate the quick temperature change from 260 °C to 0 °C.

Preparation of the co-doped CsPbCl₃ NCs with Yb³⁺ and Er³⁺

All steps and quantities were the same as those for the single doped CsPbCl₃ NCs except there was a mixture of two RE precursors with various molar ratios between YbCl₃·6H₂O and ErCl₃·6H₂O. The ratios of Yb : Er were 8 : 2, 7 : 3, 6 : 4, and 5 : 5, respectively.

Purification

Firstly, the crude solution was centrifuged at 5000 rpm for 10 min to discard the supernatant. Secondly, the precipitate was dispersed in 5 ml of toluene and then centrifuged at 12000 rpm for 10 min. Lastly, the collected precipitate was dispersed in 3 ml of toluene and centrifuged at 3000 rpm for 2 min to remove all large particles; the final pure NCs were in the supernatant.

Characterization

Fluorescence emission spectra were measured using an Omni-λ 300 monochromator/spectrometer from Zolix. Absorbance spectra were recorded by using a Shimadzu UV-2550 spectrophotometer. The morphologies of the NCs were observed using a Tecnai F20 transmission electron microscope (TEM). The actual doping levels and ratios were found using a Varian 720-ES inductively coupled plasma-optical emission spectrometer (ICP-OES). X-ray diffraction (XRD) patterns of the NCs were acquired using a Bruker D8 Advance X-ray diffractometer (Cu Kα, λ = 1.5406 Å). X-ray photoelectron spectroscopy (XPS) was performed using an ESCALAB 250 spectrometer. The visible absolute PL QYs of the samples were determined using an FLS920P fluorescence spectrometer (Edinburgh Instruments) equipped with an integrating sphere with its inner face coated with BENFLEC. Time-resolved PL lifetime measurements were carried out using a time-correlated single-photon counting (TCSPC) lifetime spectroscopy system with a picosecond pulsed diode laser (EPL-365 nm) as the single wavelength excitation light source. A comparison of the luminescence intensity of the Yb³⁺ ions and the band edge emission of the CsPbCl₃ NCs

was done using an Ocean Optics spectrometer (QE-Pro) for the measurement of the NIR PL QYs.

Results and discussion

All samples were characterized by UV-visible absorption and PL (excited using 365 nm UV light) spectroscopies. The as-prepared CsPbCl₃ NCs showed band edge absorption and luminescence spectra similar to a previous report (Fig. 1a).⁴⁰ For the doped CsPbCl₃ NCs, there are some little blue shifts. According to the Burstein–Moss effect in heavily doped n-type semiconductors, slight blue shifts of both absorption and PL positions can be attributed to the filling of the state by the donated electrons of Yb³⁺ around the bottom of the conduction band, which leads to some band gap widening.⁴¹ Their powder XRD patterns confirmed that their crystal structure still adopts the tetragonal phase (JCPDS No. PDF#18–0366) with the space group *P4mm* (Fig. 1b). There were some minor diffraction peaks (marked with *) that could be attributed to Cs₃Pb_{6.48}Cl₁₆ (JCPDS No. PDF#45–1243) or Cs₄PbCl₆ (JCPDS No. PDF#73–2477) formed at a reaction temperature of 220 °C and disappeared at higher temperatures. Besides, the peaks of other compounds, such as CsCl, YbCl₃, and PbCl₂, were not detected. The peak position of the (101) lattice plane shifted a little compared with that of the undoped sample (see the amplified view). For the samples synthesized at 260 °C and 280 °C, the peak positions progressively shifted to higher degrees, which is due to the shrinkage of the crystal lattice because of the incorporation of Yb³⁺ with a smaller ionic radius (0.086 nm) than Pb²⁺ (0.119 nm). Fig. 1c shows that the emission of the ²F_{5/2}–²F_{7/2} transition of the Yb³⁺ ions located at 986 nm with a full width at half maximum (FWHM) of 54 nm synthesized at different reaction temperatures. By using a high-resolution Omni-λ 500 spectrometer, a clear Stark split could be observed, as shown in Fig. S1 (ESI†). Obviously, when the reaction temperature was higher than 260°C, the intensity of the Yb³⁺ emission began to decrease (Fig. 1d). We attribute this phenomenon to the effect of concentration quenching just like the other lanthanide doped materials.⁴²

We synthesized uniform cube-shaped CsPbCl₃ and CsPbCl₃:Yb³⁺ NCs with similar size distributions of around 10 nm (Fig. 2a, b, d and e). The HRTEM observations also confirmed the lattice contraction, which was initially found from XRD. The wellresolved lattice fringes of the highly crystalline structures of the CsPbCl₃ and CsPbCl₃:Yb³⁺ NCs are ascertained to be 3.96 and 3.92 Å, respectively (Fig. 2c and f). Combined with the results of XRD and HRTEM, the Yb³⁺ ions were successfully doped into the crystal structure of the CsPbCl₃ NCs.

Because of the low atomic content of Yb³⁺ ions (2.0% as determined by ICP-OES), the XPS tests failed to detect the signal of the Yb³⁺ ions on the surface (Fig. S2a, ESI†). Similar results were also reported by Nam *et al.*, wherein they did not find K⁺ on the surface of their Cs_{0.925}K_{0.075}PbI₂Br crystals.¹⁹ Due to the lattice contraction in the CsPbCl₃:Yb³⁺ NCs, the chemical bonding properties among the crystal structures should have obvious changes.⁴³ Fig. 2 g-i show that the binding energies of the Cs⁺, Pb²⁺ and Cl⁻ ions become higher. For Cs 3d, it changed from 724.1 to 724.3 eV; for Pb 4f, it shifted from 138.2 to 138.3 eV; for Cl

†Electronic supplementary information (ESI) available: XPS spectra, XRD patterns and optical spectra. See DOI: [10.1039/c8tc03957g](https://doi.org/10.1039/c8tc03957g)

2p, a change from 197.6 to 197.9 eV was found. The whole XPS spectra of the CsPbCl₃ and CsPbCl₃:Yb³⁺ NCs are shown in Fig. S2b (ESI[†]). These shifts should be attributed to the doping of Yb³⁺ ions into the CsPbCl₃ NCs. The smaller Yb³⁺ ions could occupy the Pb-sites and form smaller octahedrons, leading to stronger chemical bonds among the Cs⁺, Pb²⁺ and Cl⁻ ions. These changes also improve the stability of the Yb³⁺ ion doped CsPbCl₃ NCs (discussed later).

Luminescence decay-time measurements provide additional evidence for successful insertion of Yb³⁺ ions inside the internal lattices of the CsPbCl₃ NCs. Since the surface of the CsPbCl₃ NCs has many OA and OAm ligands, they readily diminish the NIR luminescence of Yb³⁺ by the vibrations of the C–H, N–H, or O–H bonds.⁴⁴ They can also lead to shortened excited-state decay times and lower the PL QYs, if the Yb³⁺ ions are closely adjacent to the ligands.⁴⁵ From the time-resolved PL decay tests, the luminescence decay-time of the ²F_{5/2}–²F_{7/2} transition of the Yb³⁺ ions inside the CsPbCl₃ NCs was found to be 941.9 μs (Fig. 3a). This value was similar to 815.0 μs of the Yb³⁺-doped PbIn₂S₄ NCs and much longer than that of typical Yb³⁺ organic ligands complexes (~10 μs).^{44,45} Besides, Fig. 3b shows that the incorporation of Yb³⁺ into CsPbCl₃ increases the average life time of the band edge emission of the CsPbCl₃ NCs from 3.9 to 8.2 ns. For the undoped CsPbCl₃ NCs, the fitted results reveal a τ₁ of 0.7 ns (accounting for 78.8%) and a τ₂ of 11.2 ns (accounting for 21.2%). For the CsPbCl₃:Yb³⁺ NCs, the fitted results reveal a τ₁ of 1.2 ns (accounting for 53.6%) and a τ₂ of 16.3 ns (accounting for 46.4%). This slightly increased average life time elevated the band edge emission PL QY from 5.0% to 7.7%, which may be attributed to some Cl vacancies passivated by doping with the metal ions.³⁸ The highest PL QY of NIR emission from Yb³⁺ was 120.1%, calculated by a comparison of the intensity with the intrinsic excitonic emission of the CsPbCl₃:Yb³⁺ NCs. The integral intensity contrast spectrum acquired using a fiber optic spectrometer is shown in Fig. S3 (ESI[†]).

Through individually monitoring the two emission peaks from the CsPbCl₃:Yb³⁺ NCs synthesized at 260 °C, we acquired two consistent excitation spectra (Fig. 4a and b). The difference of testing ranges between them is to avoid the detection of elastic scattering of the excitation source. Therefore, the wavelength testing ranges should have no overlap with the band edge emission of the CsPbCl₃:Yb³⁺ NCs. Since Yb³⁺ ions do not exhibit characteristic absorption in the UV through visible range, the excitation spectrum monitored at NIR emission of Yb³⁺ ions should be derived from the CsPbCl₃ → Yb³⁺ energy transfer. The huge PL QY difference between the visible and NIR emissions may be attributed to the quantum cutting, and we drew an energy level chart (Fig. 4c) to explain this process.³⁸ Similar to the structured isoelectronic traps of a lanthanide ion doped GaN semiconductor,⁴⁶ the incorporation of Yb³⁺ ions may generate a defect state in the middle of the band gap of the CsPbCl₃ NCs. When the CsPbCl₃:Yb³⁺ NCs were excited using 365 nm light, the CsPbCl₃ host generated excitons and they recombined through band gaps and emitted 408 nm light. Besides, the defect state induced by the Yb³⁺ ions divided the excitonic energy into two parts. One part of the energy transferred to the first Yb³⁺ ion. Then electrons were captured by the defect state through the Auger non-radiative relaxation process. The remaining energy was released by the exciton recombined between the electron on the defect state and the hole of the valence band. This energy further excited the second Yb³⁺ ion

through an Auger non-radiative energy transfer. For the excited Yb^{3+} ions, the electrons of the $^2\text{F}_{5/2}$ level jumped to the $^2\text{F}_{7/2}$ level and generated 986 nm photons.

The photostability of the NC solutions was tested at the same concentration under continuous irradiation with a 6 W UV (365 nm) lamp. The results are shown in Fig. 5. In about 27 h, the PL intensity of the undoped CsPbCl_3 NC solution decreased by 80%, whereas it took 85 h for the $\text{CsPbCl}_3:\text{Yb}^{3+}$ NC solution to lose 80% of its PL intensity. The stability shows a great improvement because of Yb^{3+} doping.

We extended the method to synthesize Er^{3+} and $\text{Yb}^{3+}/\text{Er}^{3+}$ doped CsPbCl_3 NCs. The XRD and optical characterization results of the $\text{CsPbCl}_3:\text{Er}^{3+}$ and $\text{CsPbCl}_3:\text{Yb}^{3+}/\text{Er}^{3+}$ NCs are shown in Fig. S4-S7 (ESI[†]), respectively. Interestingly, for the single doped $\text{CsPbCl}_3:\text{Er}^{3+}$ NCs, we detected a wide-peak at 591 nm with an FWHM of 77 nm but failed to observe luminescence in the NIR range, which may be due to the formation of defect states in the band gap of the CsPbCl_3 NCs caused by Er^{3+} . However, for the double doped $\text{CsPbCl}_3:\text{Yb}^{3+}/\text{Er}^{3+}$ NCs, a luminescence peak at 1533 nm (an FWHM of 34 nm) was obtained from the $^4\text{I}_{13/2}-^4\text{I}_{15/2}$ transition of the Er^{3+} ions. This phenomenon may be attributed to doping with the Yb^{3+} ions, which suppresses the emission from the defect states and builds an energy bridge between the CsPbCl_3 host and the Er^{3+} ions. Therefore, the excitation spectrum of the $\text{CsPbCl}_3:\text{Er}^{3+}/\text{Yb}^{3+}$ NCs monitored at 1533 nm is similar to Fig. 4a and b (Fig. S6, ESI[†]). Fig. S5b (ESI[†]) shows the PL intensity changes at different feed ratios of Yb^{3+} to Er^{3+} ions under the same synthesis conditions. At a feed ratio of 7:3, we acquired the strongest NIR emission.

Conclusions

In conclusion, we have designed a feasible synthesis process to get high-efficient NIR emission with a PL QY of 127.8% ($\text{CsPbCl}_3:\text{Yb}^{3+}$ NCs) with improved stability. The difference between the undoped and doped CsPbCl_3 NCs was discussed. The 986 nm NIR emission of Yb^{3+} and 1533 nm NIR emission of Er^{3+} may have potential for applications in diode lasers and photo-communications.

Supplementary Material

Refer to Web version on PubMed Central for supplementary material.

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Fig. 1.

Optical properties and XRD characterization of the CsPbCl₃:Yb³⁺ NCs synthesized at different reaction temperatures. (a) Absorption and intrinsic emission spectra. (b) XRD patterns and amplified views around 23°. (c) NIR emission spectra and (d) integral emission intensities of the CsPbCl₃:Yb³⁺ NCs at different reaction temperatures.

Fig. 2. TEM (scale bar 50 nm) images, size distribution and HRTEM images (scale bar 5 nm) of the undoped CsPbCl₃ NCs (a–c) and CsPbCl₃:Yb³⁺ NCs (d–f), respectively. High resolution XPS spectra of the CsPbCl₃ (black) and CsPbCl₃:Yb³⁺ (red) NCs for (g) Cs 3d, (h) Pb 4f, (i) Cl 2p.

Fig. 3.

(a) Time-resolved PL decay profile of $^2F_{5/2} \rightarrow ^2F_{7/2}$ of the Yb^{3+} ions in the $\text{CsPbCl}_3:\text{Yb}^{3+}$ NCs. (b) Time-resolved band edge emission decay profiles of the CsPbCl_3 (red) and $\text{CsPbCl}_3:\text{Yb}^{3+}$ (green) NCs.

Fig. 4.

(a) Excitation spectrum of the CsPbCl₃:Yb³⁺ NCs monitored at 986 nm. (b) Excitation spectrum of the CsPbCl₃:Yb³⁺ NCs monitored at 408 nm. (c) Proposed energy transfer mechanism for the CsPbCl₃:Yb³⁺ NCs.

Fig. 5.
PL decrease of the CsPbCl₃ and CsPbCl₃:Yb³⁺ NCs under 365 nm UV light irradiation.